

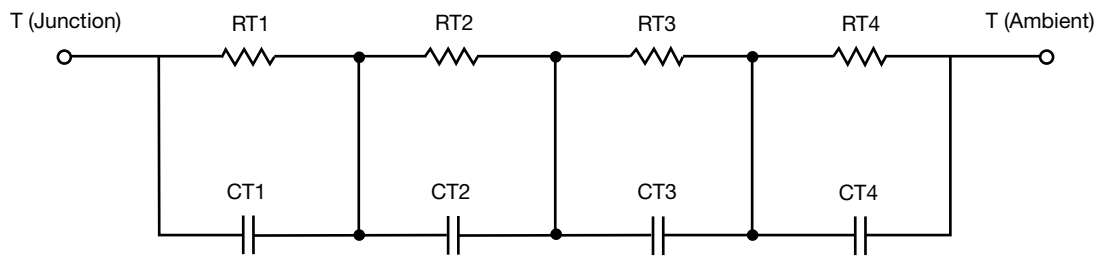
## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/tank and Cauer/filter configurations are included. When implemented in PSpice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the PSpice simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in application note AN609, "Thermal Simulation of Power MOSFETs on the PSpice Platform".

### R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RT1	5.5199	1.2365	n/a
RT2	11.5769	999.8000m	n/a
RT3	17.6842	4.1206	n/a
RT4	45.2190	143.1000m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	440.0251u	198.8699u	n/a
CT2	203.3389m	7.2601m	n/a
CT3	6.6246m	538.7673u	n/a
CT4	1.7688	52.2509m	n/a

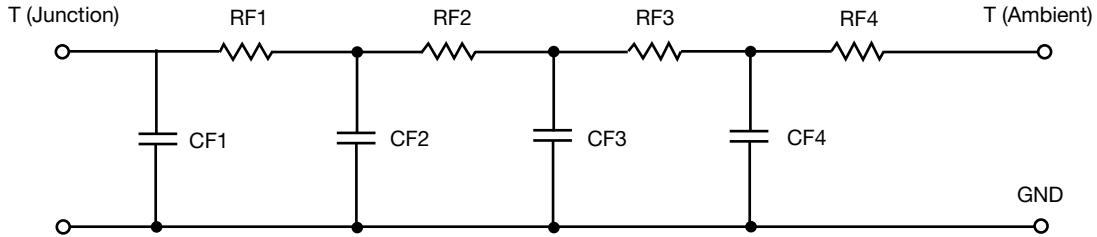
#### Note

- n/a indicates not applicable

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



R-C THERMAL MODEL FOR FILTER CONFIGURATION



R-C VALUES FOR FILTER CONFIGURATION			
THERMAL RESISTANCE (°C/W)			
Junction to	Ambient	Case	Foot
RF1	4.9502	2.6614	n/a
RF2	18.9752	3.5742	n/a
RF3	12.7811	99.9977m	n/a
RF4	43.2935	164.4023m	n/a
THERMAL CAPACITANCE (Joules/°C)			
Junction to	Ambient	Case	Foot
CF1	307.9476u	159.3819u	n/a
CF2	5.0635m	521.4187u	n/a
CF3	158.6997m	44.3088m	n/a
CF4	1.6375	207.5850u	n/a

Note

- n/a indicates not applicable

